Diode Semiconductor Device - Page 1 of 1



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	closure Material:
G	lass
0	verall Length:
0.	350 inches
т	erminal Length:
1.	000 inches
0	verall Diameter:
0.	145 inches
F	unction For Which Designed:
Ze	ener diode
М	ounting Method:
Т	erminal
Fe	eatures Provided:
н	ermetically sealed case
S	emiconductor Material:
Si	licon
V	oltage Rating In Volts Per Characteristic:
22	2.0 regulator voltage
V	oltage Tolerance In Percent:
-5	.0/+5.0
С	urrent Rating Per Characteristic:
50	0.00 milliamperes all primaries horsepower metric
P	ower Rating Per Characteristic:
5.	0 watts total device dissipation
Μ	aximum Operating Tempurature Per Measurement Point:
20	00.0 degrees celsius ambient air
Т	erminal Type And Quantity:
2	uninsulated wire lead
S	pecification Data:
80	0131-release 5750 professional/industrial association specification
S	helf Life:
N	/a
U	nit Of Measure:
D	emilitarization:
Ν	
Fi	ig:
	110a0